

DUAL-CHANNEL, WIDE BANDWIDTH, HIGH LINEARITY LOW NOISE AMPLIFIER

Package Style: QFN, 20-Pin, 5mmx5mm



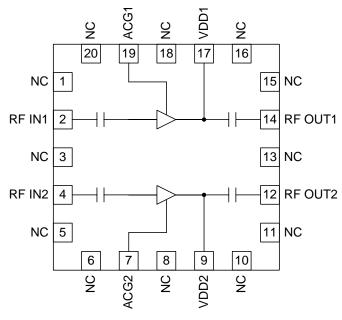


Features

- Dual-Channel
- Low Noise and High Intercept Point
- Adjustable Bias Current for Enhanced IP3
- Single 2.5V to 6.0V Power Supply
- 700 MHz to 3800 MHz Operation
- Small QFN20 5mmx5mm Package

Applications

- GSM 900, CDMA, PCS, DCS, UMTS LNA\Driver
- WLAN LNA
- General Purpose Amplification



Functional Block Diagram

Product Description

The RF3867 is a dual-channel version of the RF3863 with a low noise amplifier and a high output IP3. The amplifier is self-biased from a single voltage supply with 50Ω input and output ports. The useful frequency range is from 700MHz to 3800MHz. A 0.8dB noise figure and 36dBm OIP3 performance is achieved with a 5V V_{DD}, 180mA. Current can be increased to raise OIP3 while having minimal effect on noise figure. The IC is featured in a standard QFN, 20-pin, 5mmx5mm package.

Ordering Information

RF3867 Dual-Channel, Wide Bandwidth, High Linearity Low Noise

Amplifier

RF3867PCK-410 Fully Assembled Evaluation Board with 5 Sample Parts

1.5 GHz to 2.7 GHz

Optimum Technology Matching® Applied

| ☐ GaAs HBT | ☐ SiGe BiCMOS | ✓ GaAs pHEMT | ☐ GaN HEMT |
|---------------|---------------|--------------|------------|
| ☐ GaAs MESFET | ☐ Si BiCMOS | ☐ Si CMOS | ☐ RF MEMS |
| ☐ InGaP HBT | ☐ SiGe HBT | ☐ Si BJT | ☐ LDMOS |

RF MICRO DEVICES®, RRMO®, optimum Technology Matching®, Enabling Niroless Connectivity[®], Pavestaria, Paul Allis Willow TOTAL RADIO™ and UltimateBlue™ are trademarks of RRMO. LLC. BLUETOOTH is a trade, mark owned by Bulletindth Sill, or IL. S.A. and lingsred for view by PRMD. All idinet cride names, trademarks and resistency trademarks are for trademarks and resistency.



Absolute Maximum Ratings

| Parameter | Rating | Unit |
|--------------------------------|-----------------|-----------------|
| Supply Voltage | 6V | V _{DC} |
| Input RF Level | +10 | dBm |
| Current Drain, I _{DD} | 150 per Channel | mA |
| Operating Ambient Temperature | -40 to +85 | °C |
| Storage Temperature | -40 to +150 | °C |





Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective 2002/95/EC (at time of this document revision).

The information in this publication is believed to be accurate and reliable. However, no responsibility is assumed by RF Micro Devices, Inc. ("RFMD") for its use, nor for any infringement of patents, or other rights of third parties, resulting from its use. No license is granted by implication or otherwise under any patent or patent rights of RFMD. RFMD reserves the right to change component circuitry, recommended application circuitry and specifications at any time without prior notice.

| Davamatav | | Specification | | 11 | O - malitai - m |
|--------------|------|---------------|------|-----------|---|
| Parameter | Min. | Тур. | Max. | Max. Unit | Condition |
| High Band | | _ | | _ | |
| Frequency | 3.3 | | 3.8 | GHz | |
| Current | | 180 | | mA | V _{DD} =5V |
| Gain | | 10 | | dB | Temp=+25°C, V _{DD} =5V, I _{DD} =180 mA, 3500 MHz unless specified |
| Noise Figure | | 0.8 | | dB | |
| OIP3 | | 36 | | dBm | f ₁ =3500MHz, f ₂ =3501MHz |
| OP1dB | | 21 | | dBm | |
| S11 | | -10 | | dB | |
| S22 | | -12 | | dB | |
| Mid Band | | | | | |
| Frequency | 1500 | | 2700 | MHz | |
| Current | | 180 | | mA | V _{DD} =5V |
| Gain | 13.5 | 15.0 | 16.5 | dB | +25°C, V _{DD} =5V, I _{DD} =180 mA, 2000 MHz unless specified |
| Noise Figure | | 0.8 | 1.1 | dB | |
| OIP3 | 33.0 | 35.5 | | dBm | f ₁ =2000 MHz, f ₂ =2001 MHz |
| OP1dB | 21.0 | 22.5 | 25.0 | dBm | |
| S11 | | -10 | | dB | |
| S22 | | -14 | | dB | |
| Low Band | | | | | |
| Frequency | 700 | | 1100 | MHz | |
| Current | | 180 | | mA | V _{DD} =5V |
| Gain | | 18.5 | | dB | +25°C, V _{DD} =5V, I _{DD} =180 mA, 850 MHz unless specified |
| Noise Figure | | 1 | | dB | |
| OIP3 | | 35 | | dBm | f ₁ =850 MHz, f ₂ =851 MHz |
| OP1dB | | 22 | | dBm | |
| S11 | | -10 | | dB | |
| S22 | | -10 | | dB | |





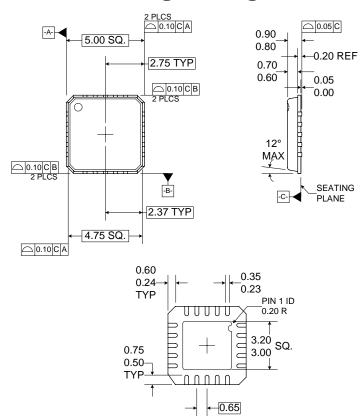
| Parameter | Specification | | | Unit | Condition | |
|--------------------------|---------------|------|-------|-----------|--|--|
| Min. Typ. | Тур. | Max. | Offic | Condition | | |
| Thermal | | | | | | |
| Theta _{JC} | | 30 | | °C/W | Dissipated power= $V_{DD}*(I_{DD1} + I_{DD2})$ | |
| Power Supply | | | | | | |
| Device Operating Voltage | 2.5 | 5.0 | 6.0 | V | | |
| Operating Current | 130 | 180 | 220 | mA | V _{DD} =5V, R2/R3=open | |



| Pin | Function | Description | Interface Schematic |
|------|----------|---|---------------------|
| 1 | NC | Not connected. | |
| 2 | RF IN1 | Channel 1 RF input pin. 50Ω matched. This pin is DC-blocked. | |
| 3 | NC | Not connected. | |
| 4 | RF IN2 | Channel 2 RF input pin. 50Ω matched. This pin is DC-blocked. | |
| 5 | NC | Not connected. | |
| 6 | NC | Not connected. | |
| 7 | ACG2 | Channel 2 AC ground. Shunt cap may be added for tuning. Shunt resistor may be added to increase I _{DD} /IP3. | |
| 8 | NC | Not connected. | |
| 9 | VDD2 | Channel 2 bias voltage. 2.5V to 6.0V applied through bias inductor. | |
| 10 | NC | Not connected. | |
| 11 | NC | Not connected. | |
| 12 | RF OUT2 | Channel 2 RF output pin. 50Ω matched. This pin is DC-blocked. | |
| 13 | NC | Not connected. | |
| 14 | RF OUT1 | Channel 1 RF output pin. 50Ω matched. This pin is DC-blocked. | |
| 15 | NC | Not connected. | |
| 16 | NC | Not connected. | |
| 17 | VDD1 | Channel 1 bias voltage. 2.5V to 6.0V applied through bias inductor. | |
| 18 | NC | Not connected. | |
| 19 | ACG1 | Channel 1 AC ground. Shunt cap may be added for tuning. Shunt resistor may be added to increase $I_{DD}/IP3$. | |
| 20 | NC | Not connected. | |
| Pkg | GND | Ground connection. | |
| Base | | | |



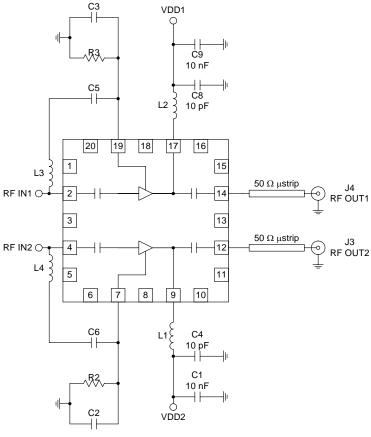
Package Drawing



Dimensions in mm.



Evaluation Board Schematic 700 MHz to 1100 MHz, 1500 MHz to 2700 MHz, and 3300 MHz to 3800 MHz



| Commonant | High Band | Mid Band | Low Band |
|-------------|----------------------|----------------------|---------------------|
| Component | 3300 MHz to 3800 MHz | 1500 MHz to 2700 MHz | 700 MHz to 1100 MHz |
| L1, L2 (nH) | 1.5 | 12 | 56 |
| L4, L3 (nH) | 100 pF | 100 pF | 22 |
| C5, C6 (pF) | 12 nH | 4.7 nH | 100 |
| C2, C3 (pF) | DNP | 12 | 6.8 |
| R2, R3 (Ω) | DNP | DNP | DNP |
| R1 (Ω) | 0 | 0 | 0 |
| | | | See note 1 |

R2 and R3 are DNP for typical 90 mA per channel current draw. If R2 or R3 is added, the channel I_{DD} will increase. A 20 Ω R2 or R3 will raise the current of a channel to achieve higher linearity.

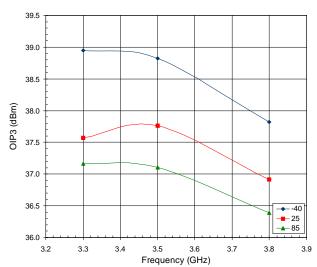
Note 1: For low band add a series 6.8 nH inductor on RF IN, and a shunt 15 nH inductor on RF OUT. Inductors should be placed as close as possible to the part.

Note 2: The topology of L3, L4, C5, and C6 in the mid and high bands. They must be as shown in the table.

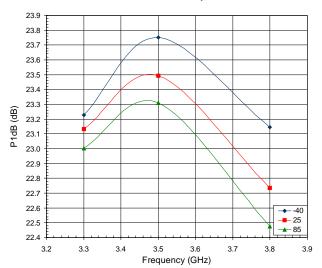




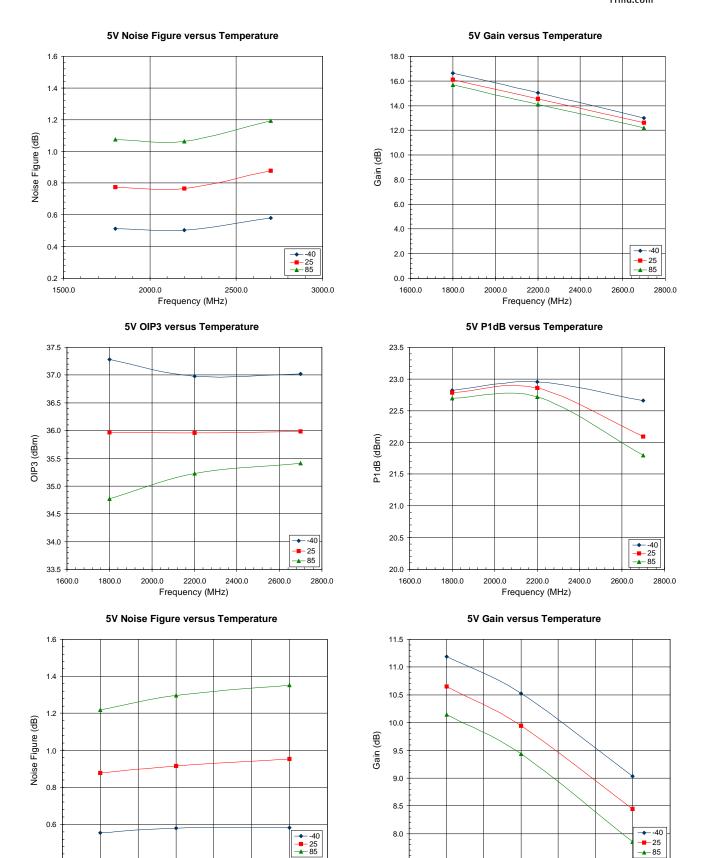




5V P1dB versus Temperature







7.5

3.2

3.3

3.4

3.5

3.6

Frequency (GHz)

0.4

3.2

3.9

3.8

3.7

3.3

3.4

3.5

Frequency (GHz)

3.6

3.7

3.8

3.9



Theory of Operation

Low noise figure/high IP3 make the RF3867 ideal for use as a dual channel receive LNA/transmit driver for cellular/DCS/PCS/UMTS and WiMax platforms in addition to many other general purpose applications. Standard evaluation boards cover 700MHz to 1100MHz, 1500MHz to 2700MHz, and 3300MHz to 3800MHz. RF3867 functions as a dual channel RF3863 equivalent.

Viewing the data sheet evaluation board schematic, refer to below for purpose/function of external components as they apply to each channel/path:

- L3/C5/C3 (L4/C6/C2): Placed to optimize input match and enhance out of band low frequency stability.
- R2 (R3): Optionally placed to increase bias current and IP3. 20Ω value is found to be the best case (see graph section of the RF3863 data sheet).
- L2/C8 (L1/C4): Influence output return loss.

RF3867 has internal DC-blocking capacitors at the RFin/RFout. In addition, impedance has been shown to be seen looking out at pins 17/19 (7/9) influence response. As a result, two port s-parameters become non-applicable. In the event matching is desired for frequency bands outside of those provided with standard evaluation boards, the following approach can be used:

- · Start with matching seen for standard evaluation board closest to desired band of operation.
- Optimize values at L3/C3/L2/C8 (L4/C2/L1/C4) to obtain response/performance.

